

PMEG10010ELR 100 V, 1 A low leakage current Schottky barrier rectifier 8 September 2016 Product dat

Product data sheet

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Average forward current: I_{F(AV)} ≤ 1 A
- Reverse voltage: V_R ≤ 100 V
- Low forward voltage: V_F = 710 mV
- High power capability due to clip-bonding technology
- Extremely low leakage current I_R = 40 nA
- High temperature T_i ≤ 175 °C •
- AEC-Q101 qualified

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply •
- Reverse polarity protection
- Low power consumption applications

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
I _{F(AV)}	average forward current	square wave; δ = 0.5 ; f = 20 kHz; T _{sp} ≤ 170 °C		-	-	1	A
V _R	reverse voltage	T _j = 25 °C		-	-	100	V
V _F	forward voltage	I_F = 1 A; $t_p \leq ~300~\mu s; ~\delta \leq ~0.02~; T_j$ = 25 $^\circ C$		-	710	770	mV
I _R	reverse current	V_R = 100 V; t _p ≤ 300 μs; T _j = 25 °C; δ ≤ 0.02		-	40	150	nA



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5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	К	cathode[1]		1 🕂 2				
2	A	anode	SOD123W	sym001				

[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
PMEG10010ELR	SOD123W	plastic surface mounted package; 2 leads	SOD123W

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMEG10010ELR	К7

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage	T _j = 25 °C		-	100	V
l _F	forward current	T _{sp} = 165 °C; δ = 1		-	1.4	А
I _{F(AV)}	average forward current	square wave; $\delta = 0.5$; f = 20 kHz; T _{amb} \leq 135 °C	[1]	-	1	A
		square wave; $\delta = 0.5$; f = 20 kHz; T _{sp} \leq 170 °C		-	1	A
I _{FSM}	non-repetitive peak forward current	square wave; t_p = 8 ms; $T_{j(init)}$ = 25 °C		-	50	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	680	mW
			[3]	-	1150	mW
			[1]	-	2140	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1][2]	-	-	220	K/W
			[1][3]	-	-	130	K/W
			<u>[1][4]</u>	-	-	70	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	18	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

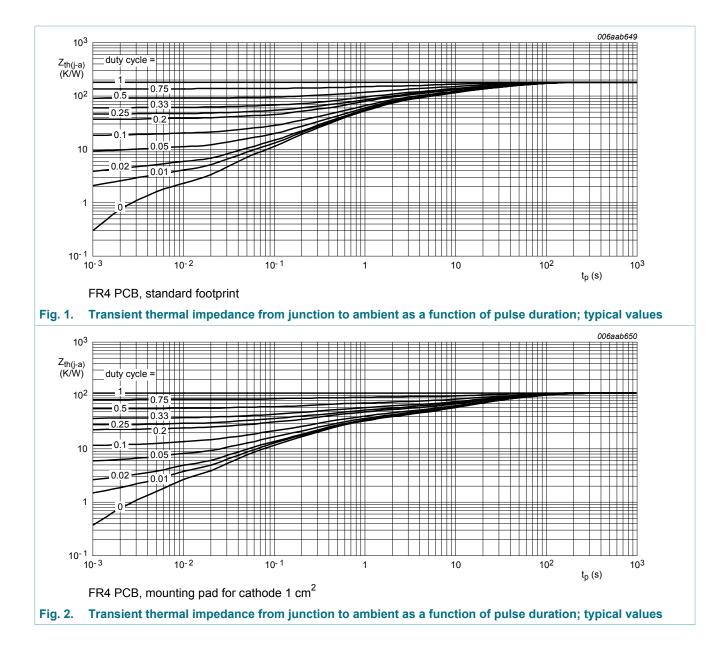
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

[4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.

[5] Soldering point of cathode tab.

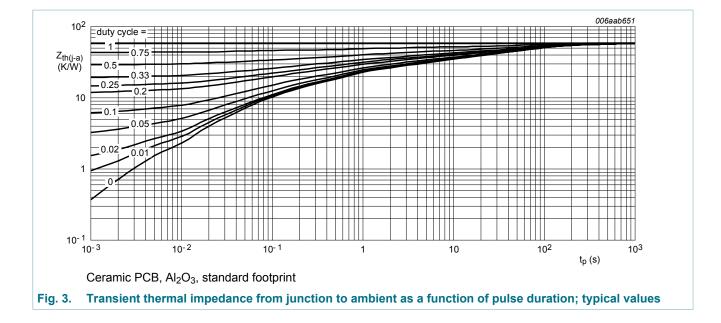
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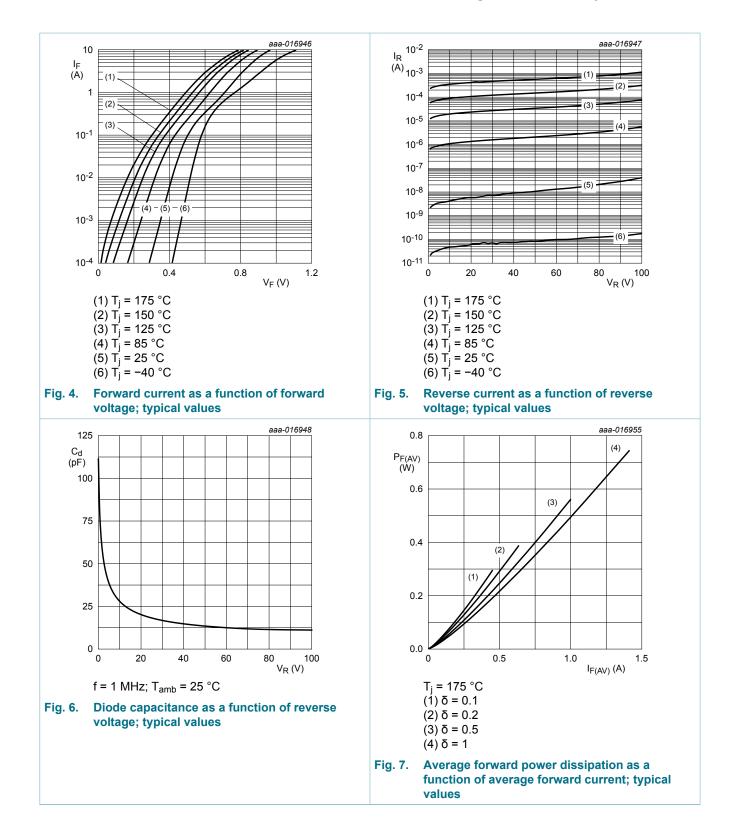


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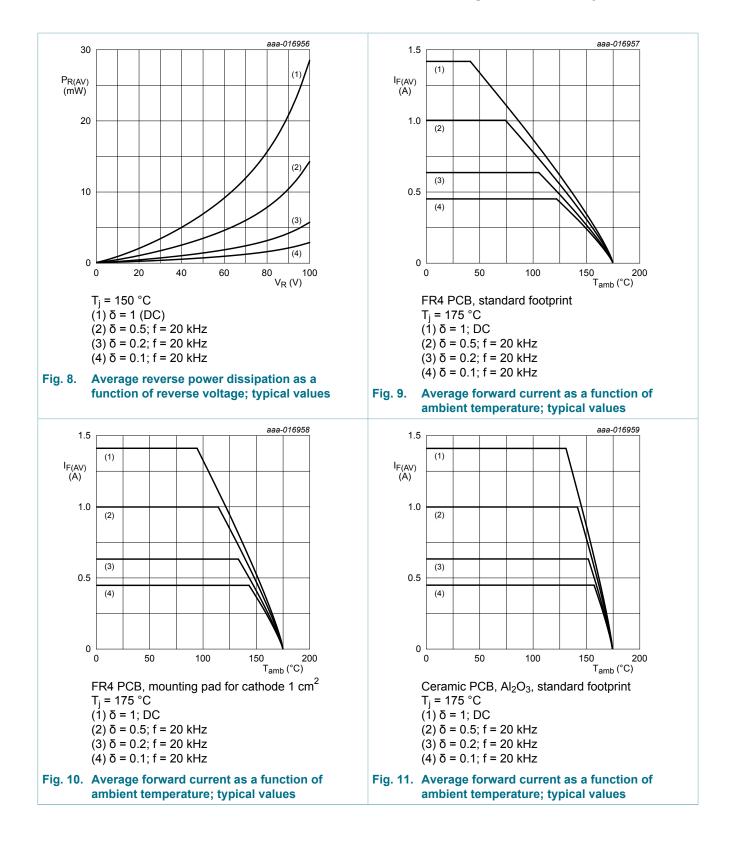
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)R}	reverse breakdown voltage	I_{R} = 1 mA; t_{p} = 300 µs; δ = 0.02 ; T_{j} = 25 °C	100	-	-	V
V _F	forward voltage	$\begin{array}{l} I_{F} = 0.1 \; A; t_{p} \leq \; 300 \; \mu s; \delta \leq \; 0.02 \; \; ; \\ T_{j} = 25 \; ^{\circ} C \end{array}$	-	505	565	mV
		$\begin{array}{l} I_{F} = 0.5 \; A; t_{p} \leq \; 300 \; \mu s; \delta \leq \; 0.02 \; \; ; \\ T_{j} = 25 \; ^{\circ} C \end{array}$	-	640	710	mV
		$\begin{array}{l} I_{F} = 0.7 \; A; t_{p} \leq \; 300 \; \mu s; \delta \leq \; 0.02 \; \; ; \\ T_{j} = 25 \; ^{\circ} C \end{array}$	-	675	740	mV
		$ \begin{array}{l} I_F = 1 \; A; t_p \leq \; 300 \; \mu s; \delta \leq \; 0.02 \; \; ; \\ T_j = 25 \; ^\circ C \end{array} $	-	710	770	mV
		$ \begin{array}{l} I_F = 1 \; A; t_p \leq \; 300 \; \mu s; \delta \leq \; 0.02 \; \; ; \\ T_j = 125 \; ^\circ C \end{array} $	-	575	680	mV
I _R	reverse current	V_R = 10 V; t _p ≤ 300 μs; T _j = 25 °C; δ ≤ 0.02	-	4	-	nA
		V_R = 60 V; t _p ≤ 300 μs; T _j = 25 °C; δ ≤ 0.02	-	12	-	nA
		V_R = 100 V; t _p ≤ 300 μs; T _j = 25 °C; δ ≤ 0.02	-	40	150	nA
		V_{R} = 100 V; $t_{p} \le$ 300 µs; T _j = 125 °C; $\delta \le$ 0.02	-	70	500	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	70	-	pF
		V _R = 4 V; f = 1 MHz; T _j = 25 °C	-	42	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	28	-	pF
trr	reverse recovery time	I_F = 0.5 A; I_R = 1 A; $I_{R(meas)}$ = 0.25 A; T_j = 25 °C	-	3.7	-	ns
V _{FRM}	peak forward recovery voltage	I_F = 0.5 A; dI _F /dt = 20 A/µs; T _j = 25 °C	-	690	-	V

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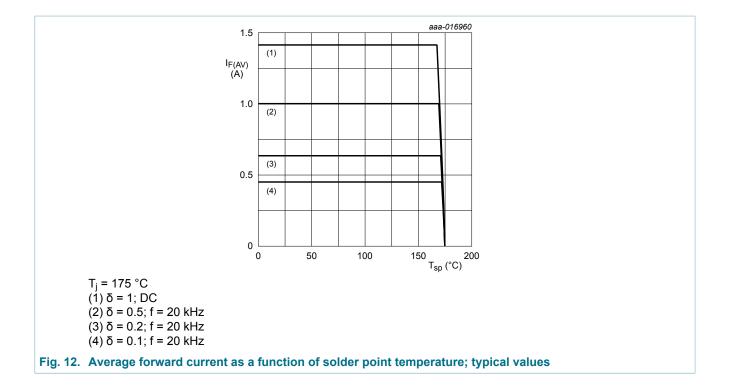


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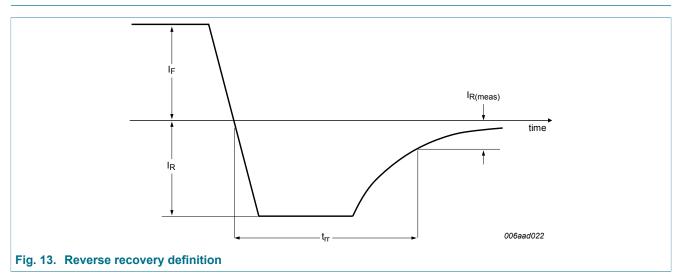


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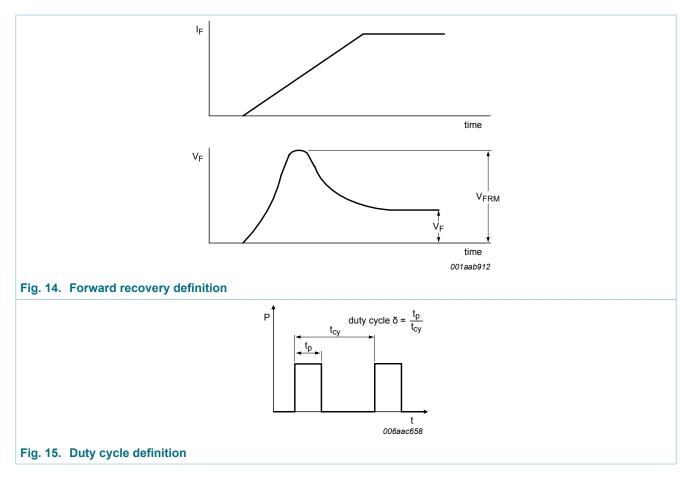


11. Test information



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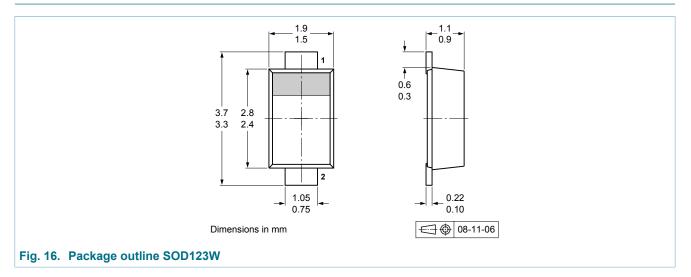
The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

Quality information

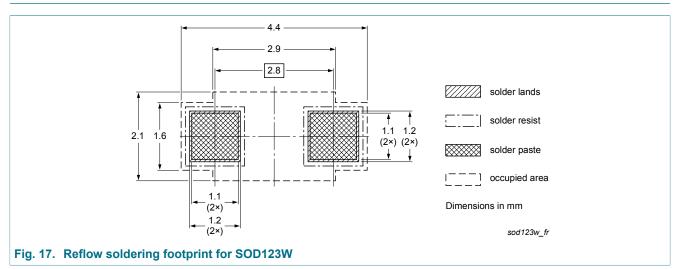
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline



13. Soldering



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14. Revision history

Table 8. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PMEG10010ELR v.3	20160908	Product data sheet	-	PMEG10010ELR v.2				
Modifications:	Figure 12: editorial change							
PMEG10010ELR v.2	20150507	Product data sheet	-	PMEG10010ELR v.1				
PMEG10010ELR v.1	20150220	Preliminary data sheet	-	-				

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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